





40V PNP HIGH GAIN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > -40V
- I_C = -5.5A High Continuous Current
- I_{CM} = -15A Peak Pulse Current
- $R_{CE(SAT)} = 29m\Omega$ for a low equivalent On-Resistance
- Low Saturation Voltage V_{CE(SAT)} < -60mV @ -1A
- hFE Specified Up to -10A for High Current Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

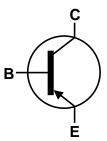
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.05 grams (Approximate)

Applications

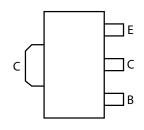
- Charging Circuits
- DC-DC Converters
- MOSFET and IGBT Gate Driving
- Power Switches
- Motor Control



Top View



Device Symbol



Top View Pin Out

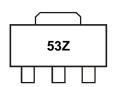
Ordering Information (Note 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZX5T3ZTA	AEC-Q101	53Z	7	12	1,000
ZX5T3ZQTA	Automotive	53Z	7	12	1,000
ZX5T3ZTC	AEC-Q101	53Z	13	12	4,000
ZX5T3ZQTC	Automotive	53Z	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- $5.\ For\ packaging\ details,\ go\ to\ our\ website\ at\ http"//www.diodes.com/products/packages.html.$

Marking Information



53Z = Product Type Marking Code





May 2013

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Base Voltage	V _{CBS}	-50	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-7.5	V
Continuous Collector Current	Ic	-5.5	Α
Peak Pulse Current	I _{CM}	-15	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		0.9		
Dower Dissipation	(Note 7)		1.5	W	
Power Dissipation	(Note 8)	P _D	2.1	VV	
	(Note 9)		3.0		
	(Note 6)		139	0000	
The second Designation of Austrian Air	(Note 7)]	83	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 8)	$R_{\theta JA}$	60		
	(Note 9)		42		
Thermal Resistance, Junction to Lead (Note 10)		R ₀ JL	2.81	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 11)

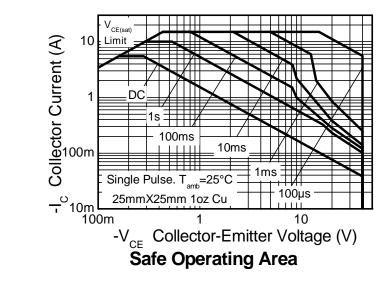
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

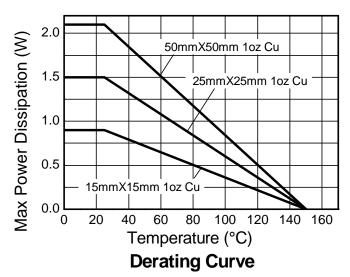
Notes:

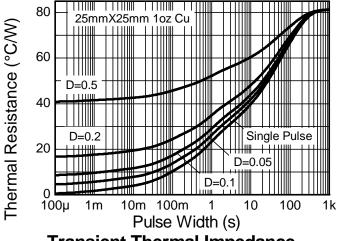
- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as note (6), except the device is mounted on $50 \text{mm} \times 50 \text{mm}$ 1oz copper.
- 9. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper and measured at t<5secs.
- 10. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

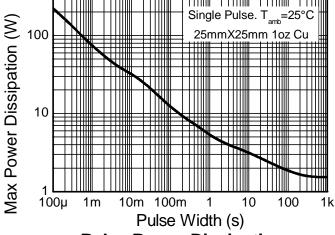


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation





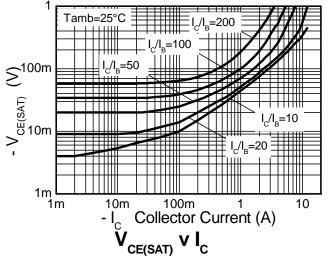
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

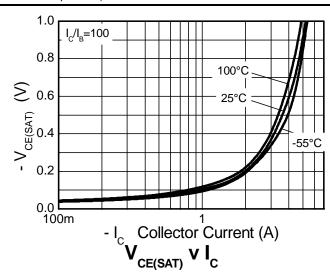
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV _{CBO}	-50	-90	_	V	I _C = -100μA	
Collector-Emitter Breakdown Voltage	BV _{CES}	-50	-90	_	V	I _C = -100μA	
Collector-Emitter Breakdown Voltage (Note 12)	BV _{CEO}	-40	-58	_	V	I _C = -10mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-7.5	-8.3	_	V	I _E = -100μA	
Collector Cutoff Current	I _{CBO}	_	<1	-20	nA	V _{CB} = -40V	
Collector Cutoff Current	I _{CES}	_	<1	-20	nA	V _{CE} = -32V	
Emitter Cutoff Current	I _{EBO}	_	<1	-20	nA	V _{EB} = -6V	
DC Current Transfer Static Ratio (Note 12)	h _{FE}	200 200 170 110	390 350 290 175	 550 	_	I _C = -10mA, V _{CE} = -2V I _C = -0.5A, V _{CE} = -2V I _C = -2A, V _{CE} = -2V I _C = -5.5A, V _{CE} = -2V	
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(SAT)}	_ _ _	-15 -44 -50 -120 -70 -125 -130 -162	-30 -60 -70 -165 -80 -175 -175	mV	$\begin{split} &I_C = -0.1A,\ I_B = -10mA \\ &I_C = -1A,\ I_B = -100mA \\ &I_C = -1A,\ I_B = -50mA \\ &I_C = -1A,\ I_B = -10mA \\ &I_C = -2A,\ I_B = -200mA \\ &I_C = -2A,\ I_B = -40mA \\ &I_C = -3.5A,\ I_B = -175mA \\ &I_C = -5.5A,\ I_B = -550mA \end{split}$	
Base-Emitter Saturation Voltage (Note 12)	V _{BE(SAT)}	_	-820 -1000	-900 -1075	V	$I_C = -2A$, $I_B = -40mA$ $I_C = -5.5A$, $I_B = -550mA$	
Base-Emitter Turn-On Voltage (Note 12)	V _{BE(ON)}	_	-778 -869	-850 -950	V	I _C = -2A, V _{CE} = -2V I _C = -5.5A, V _{CE} = -2V	
Transitional Frequency	f _T	_	152	_	MHz	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz	
Output Capacitance	C _{obo}	_	53	_	pF	V _{CB} = -10V, f = 1MHz,	
	t _d		18				
Switching Times	t _r		17	_	nC	$I_C = -1A$, $V_{CC} = -10V$	
Switching Times	ts	_	325		nS	$I_{B1} = -I_{B2} = -100 \text{mA}$	
	t _f		60				
	t _d		55	_	nS		
Switching Times	t _r		107			$I_{C} = -2A$, $V_{CC} = -30V$ $I_{B1} = -I_{B2} = -20mA$	
Switching Times	ts		264				
	t _f		103				

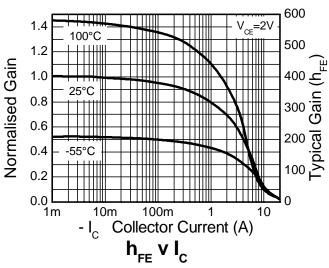
Note: 12. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

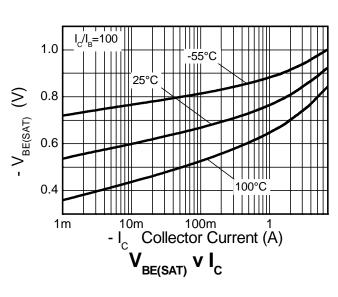


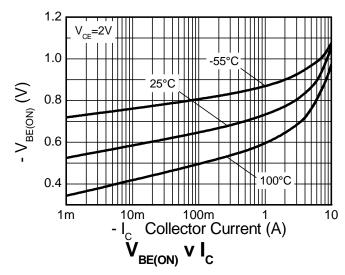
 $\textbf{Typical Electrical Characteristics} \ (@T_{A} = +25^{\circ}C, \text{ unless otherwise specified.})$







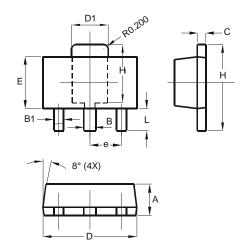






Package Outline Dimensions

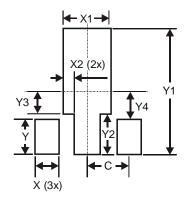
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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